REPLY UNDER 37 CFR 1.116 EXPEDITED PROCEDURE TECHNOLOGY CENTER 2800

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of: William G. America

Conf. No.: 3775

Serial No.:

10/709,776

Art Unit:

2811

Filed:

5/27/2004

Dkt. #: FIS920040083US1 (IBMF-0058)

Title: SEMICONDUCTOR DEVICE FORMED

Examiner:

Im, Junghwa M

BY IN-SITU MODIFICATION OF DIELECTRIC LAYER AND RELATED

METHODS

Mail Stop AF Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

AFTER-FINAL AMENDMENT

Sir:

INTRODUCTORY COMMENTS I.

This paper is being filed in response to the Office Action dated May 17, 2007. Please amend the above-referenced patent application as follows: Center While file on 7-17-07
Steptus

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